

TOSHIBA HIGH EFFICIENCY DIODE STACK (HED) SILICON EPITAXIAL TYPE

5DL2CZ47A, 5FL2CZ47A, 5GL2CZ47ASWITCHING TYPE POWER SUPPLY APPLICATION
CONVERTER & CHOPPER APPLICATION

Unit in mm

- Repetitive Peak Reverse Voltage : $V_{RRM}=200, 300, 400V$
- Average Output Rectified Current : $I_O=5A$
- Ultra Fast Reverse-Recovery Time : $t_{rr}=35ns$ (Max.)
- Low Switching Losses and Output Noise.

MAXIMUM RATINGS

CHARACTERISTIC		SYMBOL	RATING	UNIT
Repetitive Peak Reverse Voltage	5DL2CZ47A	V _{RRM}	200	V
	5FL2CZ47A		300	
	5GL2CZ47A		400	
Average Output Rectified Current		I _O	5	A
Peak One Cycle Surge Forward Current (Sin Wave)		I _{FSM}	25 (50Hz)	A
			27.5 (60Hz)	
Junction Temperature		T _j	−40~150	°C
Storage Temperature Range		T _{stg}	−40~150	°C
Screw Torque		—	0.6	N·m

JEDEC	—
EIAJ	—
TOSHIBA	12-10C1A

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$)

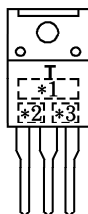
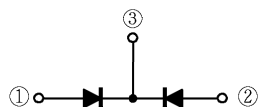
Weight : 2.0g

CHARACTERISTIC		SYMBOL	TEST CONDITION	TYP.	MAX.	UNIT
Peak Forward Voltage (Note 1)	5DL2CZ47A	V_{FM}	$I_{FM}=2.5A$	—	0.98	V
	5FL2CZ47A			—	1.3	
	5GL2CZ47A			—	1.8	
Repetitive Peak Reverse Current (Note 1)	5DL2CZ47A	I_{RRM}	$V_{RRM}=\text{Rated}$	—	10	μA
	5FL2CZ47A			—	10	
	5GL2CZ47A			—	50	
Reverse Recovery Time (Note 1)		t_{rr}	$I_F=2A, di/dt = -20A/\mu s$	—	35	ns
Forward Recovery Time (Note 1)		t_{fr}	$I_F=1A$	—	100	ns
Thermal Resistance		$R_{th(j-c)}$	DC Total, Junction to Case	—	3.8	°C/W

Note 1 : A value of one cell.

POLARITY

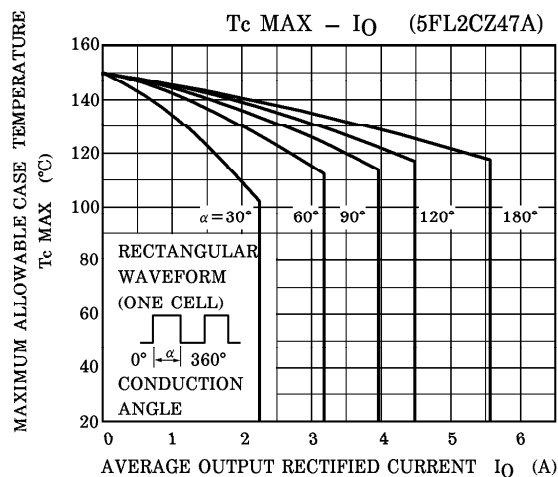
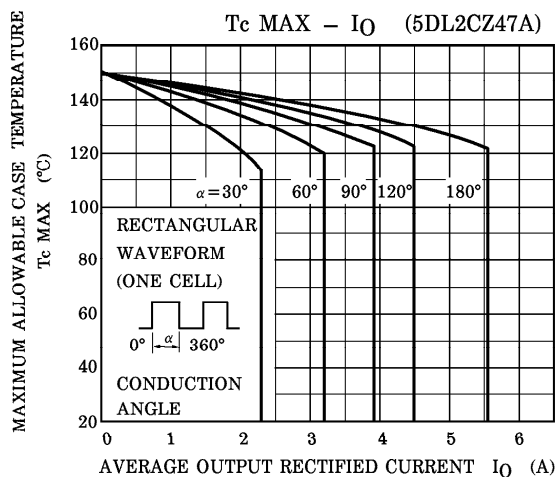
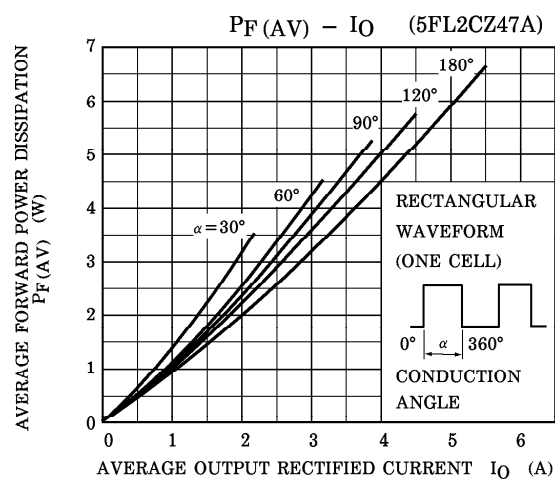
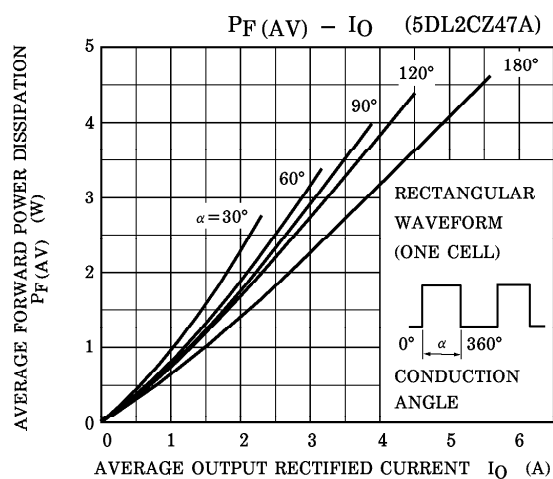
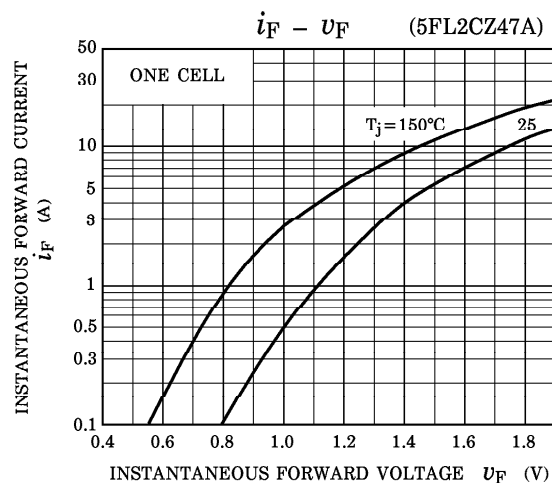
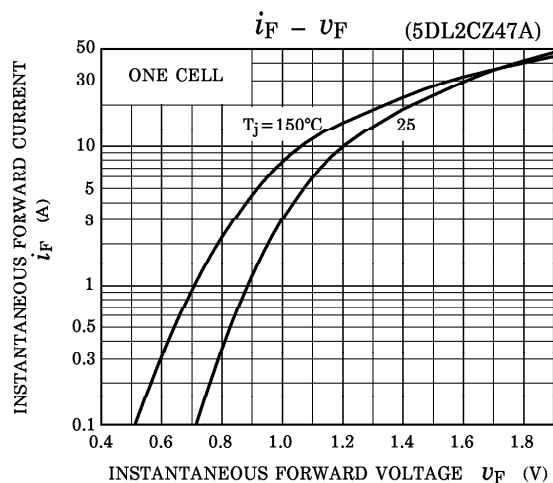
MARKING



*1	MARK	5DL2CZ	TYPE	5DL2CZ47A
		5FL2CZ		5FL2CZ47A
		5GL2CZ		5GL2CZ47A
*2	A			
*3	Lot Number			
	□ □ – Month (Starting from Alphabet A)			
	└ Year (Last Number of the Christian Era)			

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